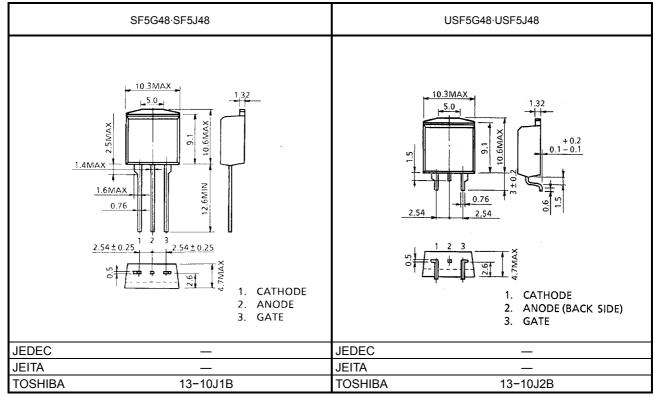
TOSHIBA THYRISTOR SILICON PLANAR TYPE

SF5G48,SF5J48,USF5G48,USF5J48

MEDIUM POWER CONTROL APPLICATIONS

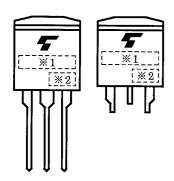
 Repetitive Peak Off-State Voltage : VDRM = 400, 600V Repetitive Peak Reverse Voltage : VRRM = 400, 600V
 Average On-State Current : IT (AV) = 5A
 Gate Trigger Current : IGT = 10mA Max.

Unit: mm



Weight: 1.7g

MARKING



*1	1	MARK	F5G48	TYPE	SF5G48, USF5G48					
1 '		WATER	F5J48	NAME	SF5J48, USF5J48					
		Lot Number								
*2	*2 Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)									



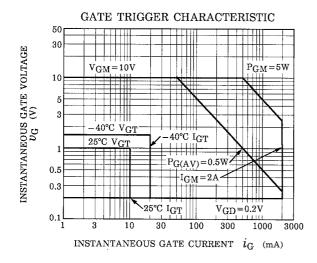
MAXIMUM RATINGS

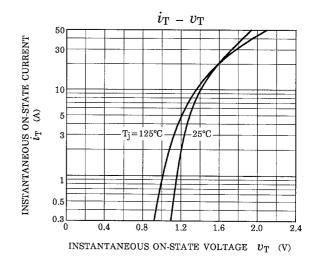
CHARACTERISTIC SF5G48 Repetitive Peak		SYMBOL	RATING	UNIT	
	SF5G48		400		
Repetitive Peak Off-State Voltage	SF5G48 USF5G48 USF5J48	400	V		
Off-State Voltage and Repetitive Peak Reverse Voltage USF5G48 VDRM VRRM Non-Repetitive Peak Reverse Voltage SF5J48 500 Non-Repetitive Peak Reverse Voltage (Non-Repetitive < 5ms T _j = 0~125°C) SF5G48 VRSM USF5J48 VRSM 720 Average On-State Current IT (AV) 5 R.M.S On-State Current IT (RMS) 7.8 Peak One Cycle Surge On-State Current (Non-Repetitive) ITSM 80 (50Hz)	600	ľ			
			000		
	SF5G48		500		
	USF5G48	\/	500	V	
	SF5J48	VRSM	720	ľ	
.,	USF5J48		720		
Average On-State Curre	ent	I _{T (AV)}	5	Α	
R.M.S On-State Curren	t	I _{T (RMS)}	7.8	Α	
	eak One Cycle Surge On-State		80 (50Hz)	А	
			88 (60Hz)		
I ² t Limit Value		I ² t	32	A ² s	
Critical Rate of Rise of On-State Current	(Note 1)	di /dt	100	A / µs	
Peak Gate Power Dissip	ation	P_{GM}	5	W	
Average Gate Power Dis	ssition	P _{G (AV)}	0.5	W	
Peak Forward Gate Volt	age	V_{FGM}	10	V	
Peak Reverse Gate Volt	age	V_{RGM}	- 5	V	
Peak Forward Gate Cur	rent	I _{GM}	2	Α	
Junction Temperature	Tj	-40~125	°C		
Strage Temperature Rai	nge	T _{stg}	-40~125	°C	

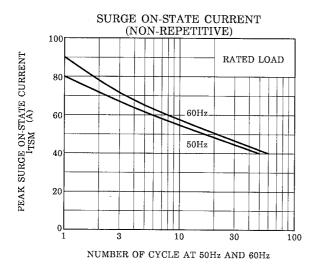
Note 1: $V_{DRM} = 0.5 \times Rated$ $I_{TM} \le 15A$ $t_{gw} \ge 10 \mu s$ $t_{gr} \le 250 ns$ $i_{gp} = I_{GT} \times 2.0$

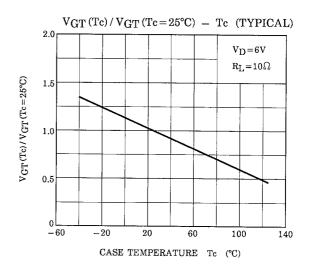
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

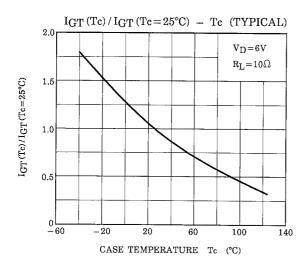
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μΑ
Peak On-State Voltage	V _{TM}	I _{TM} = 15A	_	_	1.5	V
Gate Trigger Voltage	V_{GT}	$V_D = 6V, R_L = 10\Omega$	_	_	1.0	V
Gate Trigger Current	I _{GT}	VB = 0V, NL = 1012	_	_	10	mA
Gate Non-Trigger Voltage	V_{GD}	V _D = Rated × 2 / 3, Tc = 125°C	0.2	_	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V _{DRM} = Rated, Tc = 125°C Exponential Rise	_	50	-	V / µs
Holding Current	I _H	V _D = 6V, I _{TM} = 1A	_	_	40	mA
Latching Current	Ι <u>L</u>	$V_D = 6V, f = 50Hz$ $t_{gw} = 50\mu s, i_G = 30mA$		_	50	mA
Thermal Resistance	R _{th (j-c)}	Junction to Case, DC	_	_	3.2	°C/W

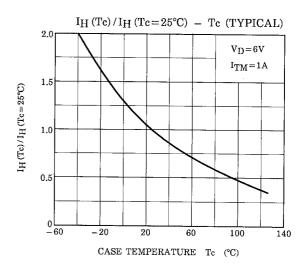


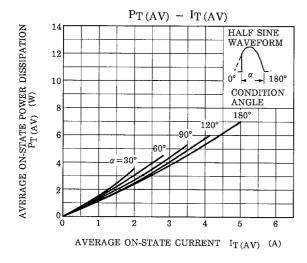


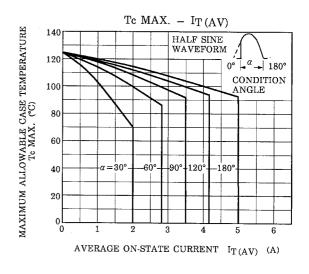


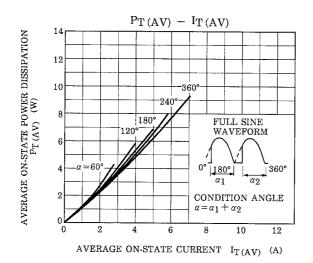


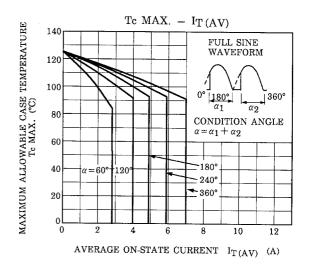


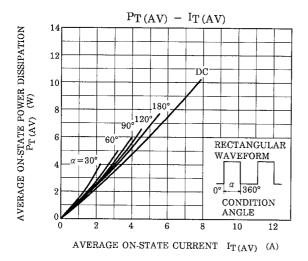


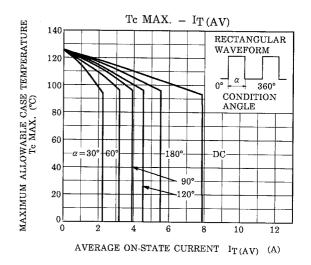




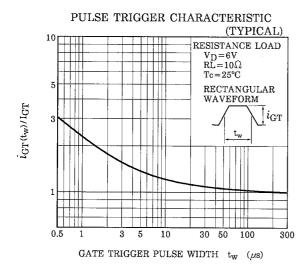


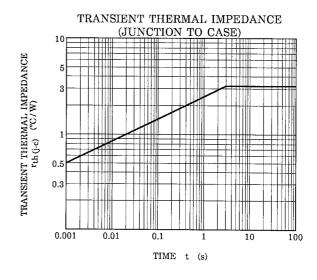






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RESTRICTIONS ON PRODUCT USE

Handbook" etc..

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